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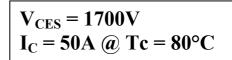


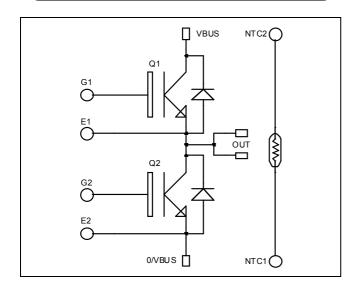






## Phase leg Trench + Field Stop IGBT3 Power Module



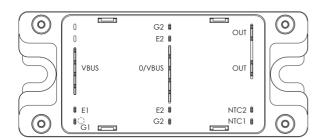


### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### **Features**

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
  - Symmetrical design
  - Lead frames for power connections
- High level of integration
- Internal thermistor for temperature monitoring



#### **Benefits**

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage		1700	V
T	Continuous Collector Current	$T_C = 25^{\circ}C$	75	
$I_{C}$	Continuous Conector Current	$T_C = 80$ °C	50	A
$I_{CM}$	Pulsed Collector Current	$T_C = 25$ °C	100	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_D$	Maximum Power Dissipation	$T_C = 25$ °C	312	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	100A @ 1600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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## All ratings @ $T_j = 25$ °C unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				250	μΑ
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		2.0	2.4	V
$V_{CE(sat)}$		$I_C = 50A$ T	$T_j = 125$ °C		2.4		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 1 \text{mA}$		5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

**Dynamic Characteristics** 

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			4400		
$C_{oes}$	Output Capacitance				180		pF
$C_{res}$	Reverse Transfer Capacitance				150		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			370		
$T_{r}$	Rise Time	$V_{GE} = 15V$			40		ns
$T_{d(off)} \\$	Turn-off Delay Time	$V_{\text{Bus}} = 900V$ $I_{\text{C}} = 50A$			650		
$T_{\mathrm{f}}$	Fall Time	$R_G = 10\Omega$			180		ı
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (	(125°C)		400		
$T_{r}$	Rise Time	$V_{GE} = 15V$			50		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 900V$ $I_{\text{C}} = 50A$			800		ns
$T_{\mathrm{f}}$	Fall Time	$R_G = 10\Omega$			300		
Eon	Turn-on Switching Energy	$\begin{vmatrix} V_{GE} = 15V \\ V_{Bus} = 900V \end{vmatrix} T_j =$	125°C		16		mI
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	$ \begin{array}{c c} I_C = 50A \\ R_G = 10\Omega \end{array} \qquad T_j =$	125°C		15		mJ

Diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Test Conditions		Тур	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1700			V
$I_{RM}$	Maximum Reverse Leakage Current $V_R=1700V$ $T_j=25^{\circ}C$ $T_j=125^{\circ}C$	V <sub>R</sub> =1700V	$T_j = 25$ °C			250	۸
1 <sub>RM</sub>			V <sub>R</sub> -1/00 V			500	μA
$I_F$	DC Forward Current		$Tc = 80^{\circ}C$		50		A
$V_{\rm F}$	Diode Forward Voltage	$I_F = 50A$	$T_j = 25^{\circ}C$		1.8	2.2	V
<b>V</b> F	Blode I of ward Voltage	1 <sub>F</sub> 3071	$T_{i} = 125^{\circ}C$		1.9		•
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25$ °C		385		ns
·rr	reverse receivery Time		$T_{j} = 125^{\circ}C$		490		113
$Q_{rr}$	Reverse Recovery Charge $V_R = 900V$		$T_j = 25$ °C		14		μС
Qrr			$T_{j} = 125^{\circ}C$		23		μ
$E_{r}$	Davanca Dagayany Enganay	·	$T_j = 25$ °C		6		mJ
$\mathbf{E}_{\mathbf{r}}$	Reverse Recovery Energy		$T_{j} = 125^{\circ}C$		12		1113



 $Temperature\ sensor\ NTC\ (see\ application\ note\ APT0406\ on\ www.microsemi.com\ for\ more\ information).$ 

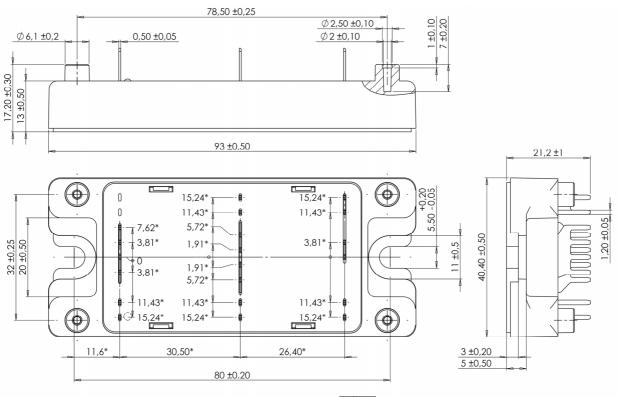
	Symbol	Characteristic	Min	Тур	Max	Unit
ſ	$R_{25}$	Resistance @ 25°C		50		kΩ
Ī	B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$
 T: Thermistor temperature R<sub>T</sub>: Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic			Mın	Тур	Max	Unit
$R_{\text{thJC}}$	Junction to Case Thermal Resistance		IGBT			0.4	°C/W
			Diode			0.7	C/ VV
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range		-40		150		
$T_{STG}$	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

### SP4 Package outline (dimensions in mm)

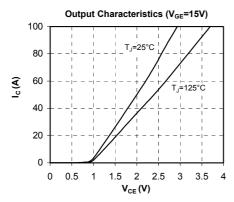


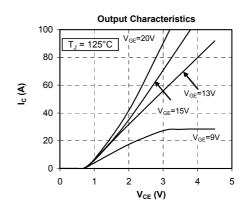
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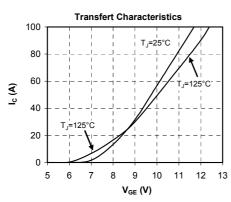
 $See \ application \ note \ APT0501 - Mounting \ Instructions \ for \ SP4 \ Power \ Modules \ on \ www.microsemi.com$ 

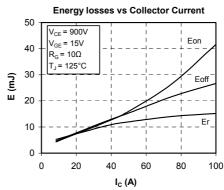


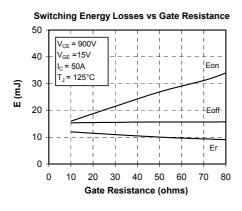
### **Typical Performance Curve**

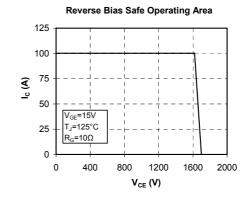


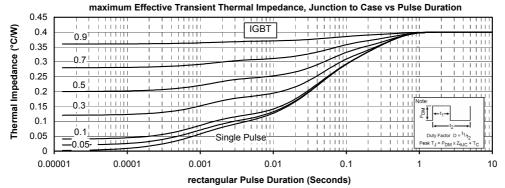




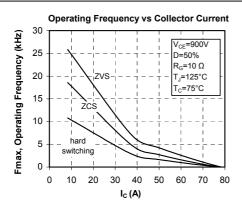


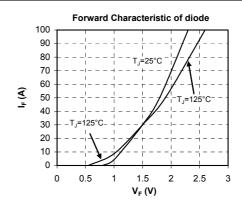


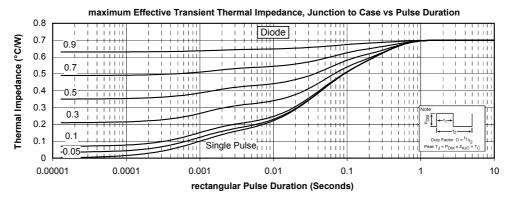














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